TOSHIBA Transistor Silicon PNP Epitaxial Type (PCT Process) Silicon NPN Epitaxial Type (PCT Process)

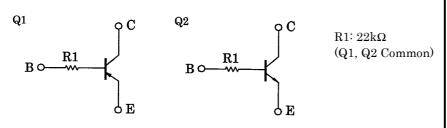
# **RN4612**

Switching, Inverter Circuit, Interface Circuit And Driver Circuit Applications

Unit in mm

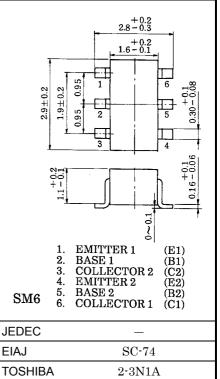
- Includeing two devices in SM6 (super mini type with 6 leads)
- With built-in bias resistors
- Simplify circuit design
- Reduce a quantity of parts and manufacturing process

#### **Equivalent Circuit and Bias Resister Values**



#### Q1 Maximum Ratings (Ta = 25°C)

Characteristic	Symbol	Rating	Unit
Collector-base voltage	$V_{CBO}$	-50	V
Collector-emitter voltage	V <sub>CEO</sub>	-50	V
Emitter-base voltage	V <sub>EBO</sub>	-5	V
Collector current	Ic	-100	mA



Weight: 0.015g

#### Q2 Maximum Ratings (Ta = 25°C)

Characteristic	Symbol	Rating	Unit
Collector-base voltage	V <sub>CBO</sub>	50	V
Collector-emitter voltage	V <sub>CEO</sub>	50	V
Emitter-base voltage	V <sub>EBO</sub>	5	V
Collector current	IC	100	mA

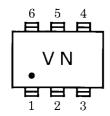
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### Q1, Q2 Common Maximum Ratings (Ta = 25°C)

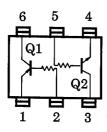
Characteristic	Symbol	Rating	Unit
Collector power dissipation	P <sub>C</sub> *	300	mW
Junction temperature	Tj	150	°C
Storage temperature range	T <sub>stg</sub>	-55~150	°C

<sup>\*</sup> Total rating

### Marking



### **Equivalent Circuit (Top View)**



2

#### Q1 Electrical Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Circuit	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I <sub>CBO</sub>	_	$V_{CB} = -50V$ , $I_E = 0$	_	_	-100	nA
Emitter cut-off current	I <sub>EBO</sub>	_	$V_{EB} = -5V, I_C = 0$	_	_	-100	mA
DC current gain	h <sub>FE</sub>	_	$V_{CE} = -5V, I_{C} = -1mA$	120	_	400	_
Collector-emitter saturation voltage	V <sub>CE (sat)</sub>	_	$I_C = -5mA$ , $I_B = -0.25mA$	_	-0.1	-0.3	V
Transition frequency	f <sub>T</sub>	_	$V_{CE} = -10V, I_{C} = -5mA$	_	200	_	MHz
Collector output capacitance	C <sub>ob</sub>	_	$V_{CB} = -10V$ , $I_E = 0$ , $f = 1MHz$	_	3	6	pF

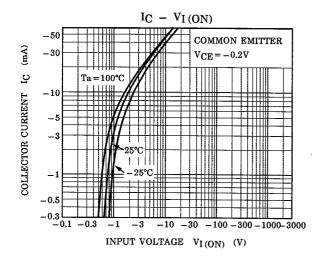
# Q2 Electrical Characteristics (Ta = 25°C)

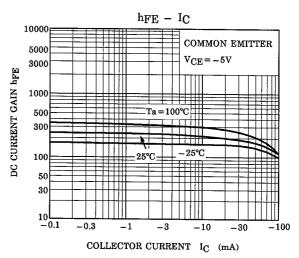
Characteristic	Symbol	Test Circuit	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I <sub>CBO</sub>	_	V <sub>CB</sub> = 50V, I <sub>E</sub> = 0	_	_	100	nA
Emitter cut-off current	I <sub>EBO</sub>	_	$V_{EB} = 5V, I_{C} = 0$	_	_	100	mA
DC current gain	h <sub>FE</sub>	_	$V_{CE}$ = 5V, $I_C$ = 1mA	120	_	700	_
Collector-emitter saturation voltage	V <sub>CE (sat)</sub>	_	I <sub>C</sub> = 5mA, I <sub>B</sub> = 0.25mA	_	0.1	0.3	V
Transition frequency	f <sub>T</sub>	_	V <sub>CE</sub> = 10V, I <sub>C</sub> = 5mA	_	250	_	MHz
Collector output capacitance	C <sub>ob</sub>	_	V <sub>CB</sub> = 10V, I <sub>E</sub> = 0, f = 1 MHz	_	3	6	pF

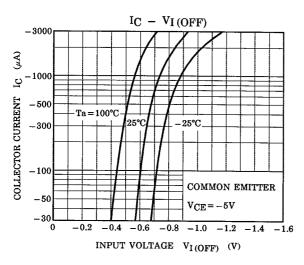
# Q1, Q2 Common Electrical Characteristics (Ta = 25°C)

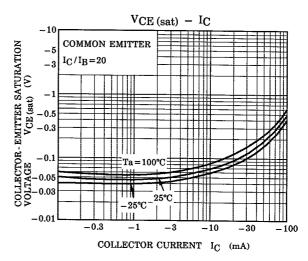
Characteristic	Symbol	Test Circuit	Test Condition	Min	Тур.	Max	Unit
Input resistor	R1	_	_	15.4	22	28.6	kΩ

Q1

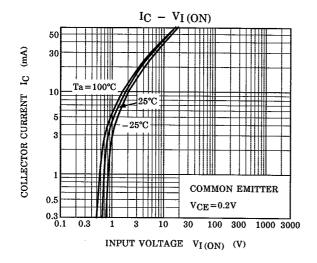


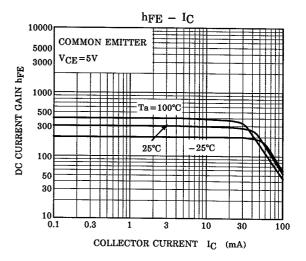


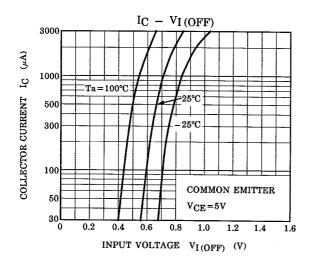


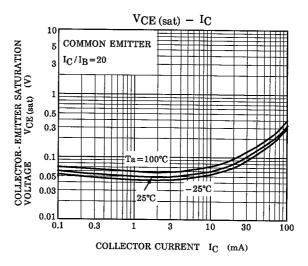


Q2









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